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APR 19 2001

In re patent application  
TC 2800 MAIL ROOM

Guhn et al.

Serial No.: 09/755,164

Group Art Unit: Not yet assigned

Filing Date: January 8, 2001

Examiner: Not yet known

For: ALUMINUM NITRIDE AND ALUMINUM OXIDE/ALUMINUM NITRIDE  
HETEROSTRUCTURE GATE DIELECTRIC STACK BASED FIELD EFFECT  
TRANSISTORS AND METHOD FOR FORMING SAME

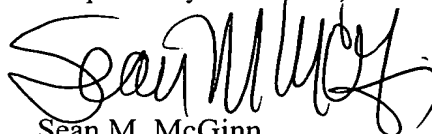
Assistant Commissioner of Patents  
Washington, D.C. 20231

### SUBMISSION OF FORMAL DRAWINGS

Sir:

Submitted herewith are (2) sheets of formal drawings comprising figures 1 - 4 for the above-identified patent application. Please substitute these formal drawings for the drawings which were filed with the application.

Respectfully submitted,

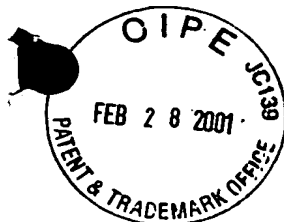


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